RENESAS

RJH1DF7RDPQ-80

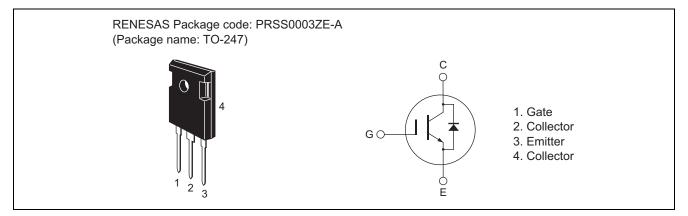
Silicon N Channel IGBT High Speed Power Switching

R07DS0413EJ0100 Rev.1.00 May 18, 2011

Features

- Voltage resonance circuit use
- Reverse conducting IGBT with monolithic body diode
- High efficiency device for induction heating
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.95$ V typ. (at $I_C = 35$ A, $V_{GE} = 15$ V, $Tj = 25^{\circ}C$)
- Gate to emitter voltage rating ± 30 V
- Pb-free lead plating

Outline



Absolute Maximum Ratings

0			$(Tc = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
tage	V _{CES}	1350	V
	V _{GES}	±30	V
Tc = 25°C	Ι _C	60	А
Tc = 100°C	Ι _C	35	А
	ic(peak) ^{Note1}	100	А
de forward current	i _{DF}	25	А
	Pc	250	W
al impedance	өј-с	0.5	°C/W
	Tj	150	°C
	Tstg	-55 to +150	°C
	Item tage $Tc = 25^{\circ}C$ $Tc = 100^{\circ}C$ de forward current	Item Symbol tage V_{CES} V_{GES} V_{GES} $Tc = 25^{\circ}C$ I_C $Tc = 100^{\circ}C$ I_C ic(peak) Note1 ic(peak) Note1 de forward current i_{DF} P_C al impedance θ_j -c Tj Tj	$\begin{array}{c c c c c c c c } \hline Item & Symbol & Ratings \\ \hline tage & V_{CES} & 1350 \\ \hline tage & V_{GES} & \pm 30 \\ \hline \hline Tc = 25^{\circ}C & I_{C} & 60 \\ \hline Tc = 100^{\circ}C & I_{C} & 35 \\ \hline Tc = 100^{\circ}C & I_{C} & 35 \\ \hline \hline tc(peak)^{Note1} & 100 \\ \hline tc & I_{DF} & 25 \\ \hline \hline P_{C} & 250 \\ \hline tc & 0.5 \\ \hline \hline tc & 0.5 \\ \hline \hline Tj & 150 \\ \hline \end{array}$

Notes: 1. Pulse width limited by safe operating area.



Electrical Characteristics

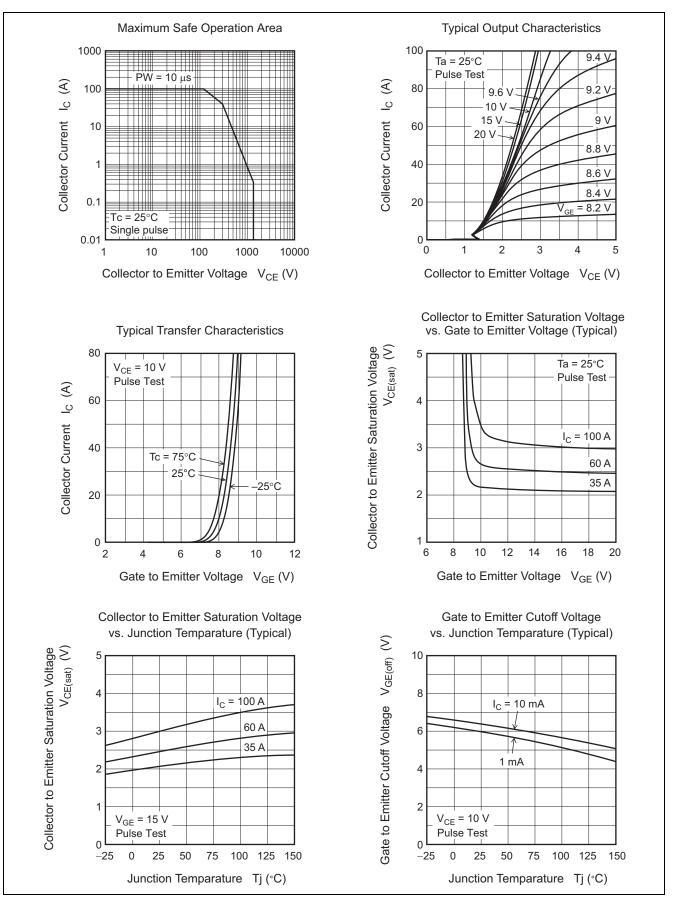
$(1) = 25^{\circ}C$	(Tj	$= 25^{\circ}C)$
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ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}		_	100	μA	$V_{CE} = 1350 \text{ V}, \text{ V}_{GE} = 0$
Gate to emitter leak current	I _{GES}			±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	3.5	—	7.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}		1.95	2.55	V	$I_C = 35$ A, $V_{GE} = 15$ V ^{Note2}
Input capacitance	Cies		3330	_	pF	V _{CE} = 25 V
Output capacitance	Coes		62		pF	V _{GE} = 0 V f = 1 MHz
Reverse transfer capacitance	Cres		50	_	pF	
Switching time	t _{d(on)}		58	_	ns	I _C = 35 A
-	tr		78		ns	$V_{CE} = 600 \text{ V}, V_{GE} = 15 \text{ V}$ Rg = 5 Ω^{Note2} Resistive Load
	t _{d(off)}		144	_	ns	
	t _f	_	208	_	ns	
C-E diode forward voltage	V _F	_	3.4	4.4	V	$I_F = 10 A^{Note2}$

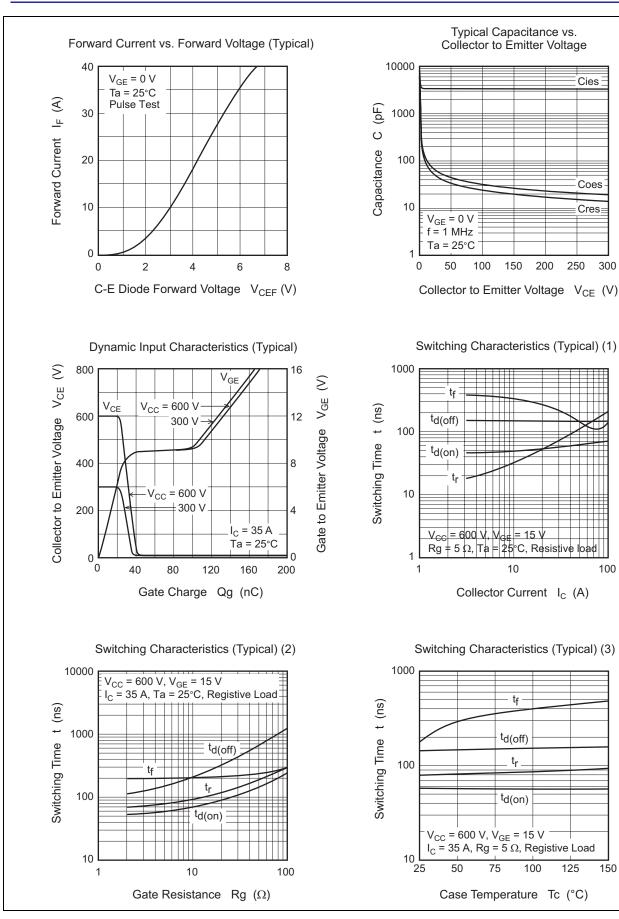
Notes: 2. Pulse test



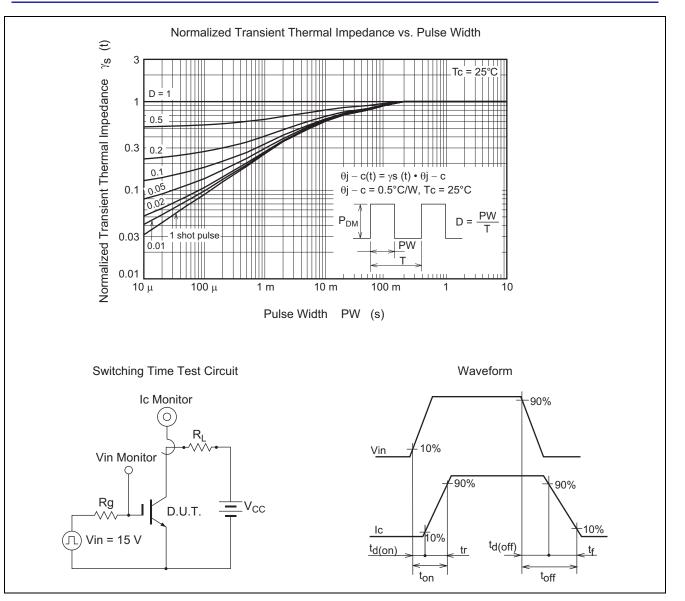
Main Characteristics





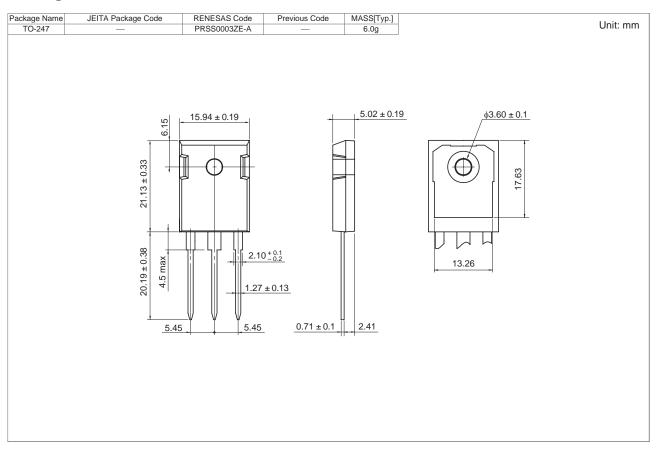








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1DF7RDPQ-80-T2	450 pcs	Box (Tube)



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